NSN 5961-01-212-8014

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View Online at https://aerobasegroup.com/nsn/5961-01-212-8014 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1400.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 4.0 small-signal short-circuit forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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